

Universal Three State Output Eight Bus Signal Transceiver

FEATURES

- CMOS process
- **Three-State Outputs**
- Eight Bus Signal Transceiver
- **Excellent ESD Characteristics**
- Package: TSSOP20、QFN20-3*3

GENERAL DESCRIPTION

DP245D is a high-speed Si-gate CMOS device and is pin compatible with Low-Power Schottky TTL (LSTTL).

DP245D is a three state output, eight bus signal Bidirectional Transceiver with two control terminals (, DIR); DIR is the data Direction Control control terminal, When DIR is high level, the data flow is a to b; When DIR is low, the data flow direction is B to A. is the output state control terminal. When is at high level, the output is in high resistance state; When is at low level, the data is transmitted normally.

DP245D is mainly used in large screen display and other consumer electronic products.

ORDERING INFORMATION

Name	Package	Mode	Reels	MSL
	TSSOP20		5000	MSL=3
DP245D	QFN20-3*3	Таре	5000	IVISL-5

APPLICATIONS

- LED Video display
- Standard 74HC245 Application
- Drive of other digital circuits

2024/11/11 www.depuw.com DP245D REV1.7 EN The content of the document is a trade secret, without permission, any organization or individual shall not be copied and disseminated in any form!



PRODUCT DESCRIPTION

> Pin Configuration



TSSOP20



> Pin Description

Pin No.	Pin Name	Function (TSSOP20)				
20	VDD	Power Supply				
10	GND	Power Ground				
1	DIR	Direction Control DIR=1, A—>B DIR=0, B—>A				
19	OE	Output Enable				
2~9	A0 ~ A7	Data Input/Output				
18~11	B0 ~ B7	Data Input/Output				
	~					
Pin No.	Pin Name	Function (TSSOP20)				
1	DIR	Direction Control DIR=1, A—>B DIR=0, B—>A				
2~9	A0 ~ A7	Data Input/Output				
10	GND	Power Ground				
18~11	B0 ~ B7	Data Input/Output				
19	OE	Output Enable				
20	VDD	Power Supply				



> Marking Information





TSSOP20 DP245D is product name:

XXXXXX The first X represents the last bit of year, for example X is 4 when year is 2014. The second X represents month, using 12 alphabets from A to L. The forth X represents day, using numbers 01 to 31. The last two X represent twafer batch no

Absolute Maximum Ratings_(Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power Supply	VDD	-0.5 ~ +8.0	V
Input Voltage	VI	-0.5 ~ VDD +0.5	V
Power Dissipation	PD	<400	mW
Max Frequency	fmax	60	MHz
Junction Temperature	Тј	150	°C
Operating Temperature	Topr	-40 ~ 85	°C
Storage Temperature	Tstg	-55 ~ 150	°C

Note:

- 1. All the voltage value setting based on GND PIN as reference;
- 2. Application exceed the above specified value, may cause permanent damage to components, extending the operating life under absolute maximum conditions may reduce the reliability of the components. These are only part of the specified values, and do not support the functional operation of other conditions beyond the specification.
- 3. SMD components, soldering peak temperature must be lower than 260°C, temperature curve as standard J-STD-020, and factory decides by itself, take the reference by actual situation and solder paste manufacture' s suggestion.

ESD Rating (T=25°C)

Symbol	Condition		Min	Тур	Max	Unit
	Charged-Device Model (CDM) ¹	All Pin-GND		±4		КV
V(ESD)	Human-Body Model (HBM) ²	All Pin-GND		±8		КV
	Machine Model (MM) ³	All Pin-GND		±0.8		KV

• [1] The minimum CDM model ESD voltage of all pins complies with ESDA STM5.3.1-1999 CLASS-C7 standard.

• [2] The minimum HBM model ESD voltage of all pins complies with ESDA STM5.1-2001 CLASS-3B standard.

• [3] The minimum HH model ESD voltage of all pins complies with ESDA STM5.2-1999 CLASS-M4 standard.

2024/11/11 DP245D REV1.7 EN

www.depuw.com

3

The content of the document is a trade secret, without permission, any organization or individual shall not be copied and disseminated in any form!



BLOCK DIAGRAM

2024/11/11



www.depuw.com



ELECTRICAL CHARACTERISTICS(T=25°C)

characteristics	Condition	Symbol	Min	Тур	Max	Unit
Power Supply		VDD	2.6	5.0	5.5	V
			-	0.5*VDD	0	V
Flip Voltage	VDD=3.3V		-	1.75	-X	v
	VDD=5V	VREV	-	2.5	-	V
	VDD=5V		-	-	1.5	V
High Level Logic Output Voltage	VDD=5V	VOH	4.9	- 4	5	V
High Level Logic Output Voltage	VDD=5V	VOL	-	0	0.1	V
High Level Current Drive Capability	VDD=5V	ЮН	-	75	-	mA
Low Level Current Drive Capability	VDD=5V	IOL		78	-	mA

DYNAMIC CHARACTERISTICS(T=25°C, f=5MHz)

	Grandinal	Cond	ition	R.A.S.	Tur	Max	11
Characteristics	Symbol	VDD(V)	CL(pF)	Min	Тур	Мах	Unit
		3.3	15	8.4	8.35	8.6	ns
Propagate rise delay	tPLH	3.3	50	8.2	8.5	8.8	ns
		5	15	5.6	6.65	7.6	ns
	0	5	50	6.4	6.65	6.8	ns
		3.3	15	7.4	7.85	8.2	ns
		5.5	50	7.4	8	8.6	ns
Propagate fall delay	tPHL	5	15	5.6	5.95	6.2	ns
			50	5.8	6	6.4	ns
		2.2	15	5.4	6	6.4	ns
Output rise time	tr	3.3	50	5.8	6.3	6.8	ns
		5	15	4.6	5.6	6.4	ns
		5	50	5.8	6.5	7.6	ns

2024/11/11 DP245D_REV1.7_EN

www.depuw.com

5

The content of the document is a trade secret, without permission, any organization or individual shall not be copied and disseminated in any form!



DP245D

6

Universal Three State Output Eight Bus Signal Transceiver

		3.3	15	4.4	5.35	6.6	ns
Output fall time			50	6.4	6.8	7	ns
Output fall time	tf 5	F	15	4.4	5.15	6.4	ns
		5	50	6	6.25	6.4	ns

DYNAMIC CHARACTERISTICS (T=85°C, f=5MHz)

Characteristics	Symbol	Cond	Condition		C _T O	Max	11
Characteristics	Symbol	VDD(V)	CL(pF)	Min	Тур	Мах	Unit
Propagate rise delay		2.2	15	9.2	9.65	10.2	ns
	tPLH	3.3	50	8.2	8.5	8.8	ns
Topagate fise delay		5	15	7.8	8.1	8.4	ns
		5	50	6.8	7.05	7.2	ns
Propagate fall delay		3.3	15	8.8	9.25	9.8	ns
	tPHL -	3.3	50	8	8.55	8.8	ns
		5	15	6.8	7	7.2	ns
			50	6.2	6.55	7.2	ns
			15	6.6	7.5	8.8	ns
	tr	3.3	50	7.8	8.2	8.8	ns
Output rise time		5	15	5.2	6.1	7.2	ns
			50	5.8	6	6.4	ns
	NO.	2.2	15	7.2	7.85	8.2	ns
Output fall time	K	3.3	50	7.2	7.3	7.6	ns
	tf		15	6.8	7.2	7.4	ns
		5	50	7	7.15	7.4	ns



TIMING DIAGRAM



FUNCTION TABLE

Output Enable	Direct Control			
Ē	DIR	エ Working Condition		
L	Н	An input Bn output		
L	L	Bn input An output		
н	X	Z		

2024/11/11 www.depuw.com 7 DP245D_REV1.7_EN The content of the document is a trade secret, without permission, any organization or individual shall not be copied and disseminated in any form!



PACKAGE DIMENSION



2024/11/11 DP245D_REV1.7_EN

www.depuw.com

8

The content of the document is a trade secret, without permission, any organization or individual shall not be copied and disseminated in any form!



PACKAGE DIMENSION

QFN20-3*3



Symbol	Min	Nom	Мах		
A	0.70	0.75	0.80		
A1	0.00	0.02	0.05		
A3		0.203REF			
b	0.15	0.20	0.25		
D	2.90	3.00	3.10		
E	2.90	3.00	3.10		
D1	1.55	1.65	1.75		
E1	1.55	1.65	1.75		
е	0.40BSC				
L	0.35	0.40	0.45		
К	0.275REF				

2024/11/11 www.depuw.com DP245D_REV1.7_EN The content of the document is a trade secret, without permission, any organization or individual shall not be copied and disseminated in any form!



OFFICIAL ANNOUNCEMENT

Division I will ensure the accuracy and reliability of the product specification document, but we reserve the right to independently modify the content of the specification document without prior notice to the customer. Before placing an order, customers should contact us to obtain the latest relevant information and verify that this information is complete and up-to-date. All product sales are subject to the sales terms and conditions provided by our company at the time of order confirmation.

Division I will periodically update the content of this document. Actual product parameters may vary due to differences in models or other factors. This document does not serve as any express or implied guarantee or authorization.

The product specification does not include any authorization for the intellectual property owned by our company or any third party. With respect to the information contained in this product specification, we make no explicit or implied warranties, including but not limited to the accuracy of the specification, its fitness for commercial use, suitability for specific purposes, or non-infringement of our company's or any third party's intellectual property. We also do not assume any responsibility for any incidental or consequential losses related to this specification document and its use.

We do not assume any obligations regarding application assistance or customer product design. Customers are responsible for their own use of our company's products and applications. In order to minimize risks associated with customer products and applications, customers should provide thorough design and operational safety validation.

The reproduction, transmission or use of this document or its contents is not permitted without express written authority. Once discovered, the company will pursue its legal responsibility according to law and compensate for all losses caused to the company.

Please note that the product is used within the conditions described in this document, paying particular attention to the absolute maximum rating, operating voltage range, and electrical characteristics. The Company shall not be liable for any damage caused by malfunctions, accidents, etc. caused by the use of the product outside the conditions stated in this document.

Division I has been committed to improving the quality and reliability of products, but all semiconductor products have a certain probability of failure, which may lead to some personal accidents, fire accidents, etc.When designing products, pay full attention to redundancy design and adopt safety indicators, so as to avoid accidents.

When using our chips to produce products, Division I shall not be liable for any patent dispute arising from the use of the chip in the product, the specification of the product, or the country of import, etc., in the event of a patent dispute over the products including the chip.